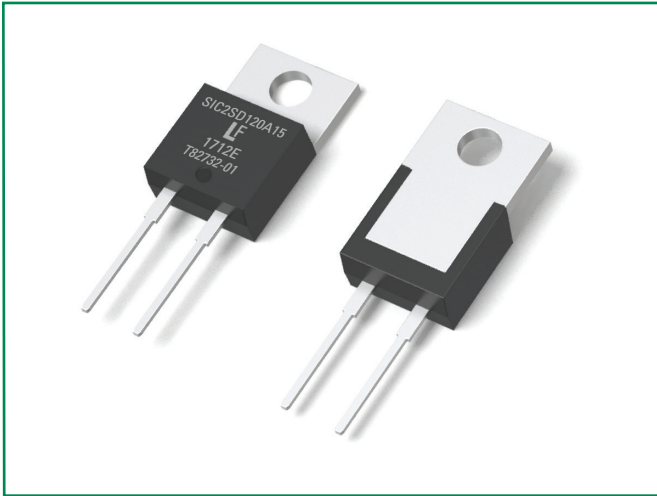


**LSIC2SD120A15**



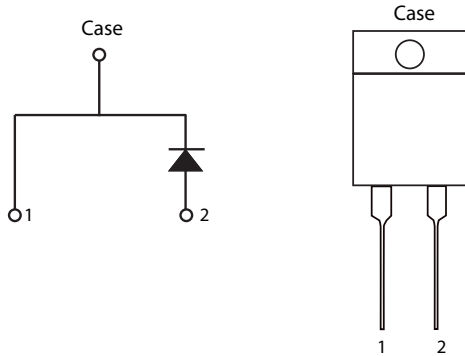
**Description**

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

**Features**

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

**Circuit Diagram TO-220-2L**



**Applications**

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

**Environmental**

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = Pb-free lead plating

**Maximum Ratings**

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	$V_{RRM}$	-	1200	V
DC Blocking Voltage	$V_R$	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current	$I_F$	$T_C = 25\text{ °C}$	44	A
		$T_C = 135\text{ °C}$	21	
		$T_C = 150\text{ °C}$	15	
Non-Repetitive Forward Surge Current	$I_{FSM}$	$T_C = 25\text{ °C}, T_P = 10\text{ ms}, \text{Half sine pulse}$	120	A
Power Dissipation	$P_{Tot}$	$T_C = 25\text{ °C}$	214	W
		$T_C = 110\text{ °C}$	93	
Operating Junction Temperature	$T_J$	-	-55 to 175	°C
Storage Temperature	$T_{STG}$	-	-55 to 150	°C
Soldering Temperature	$T_{sold}$	-	260	°C

**Electrical Characteristics**

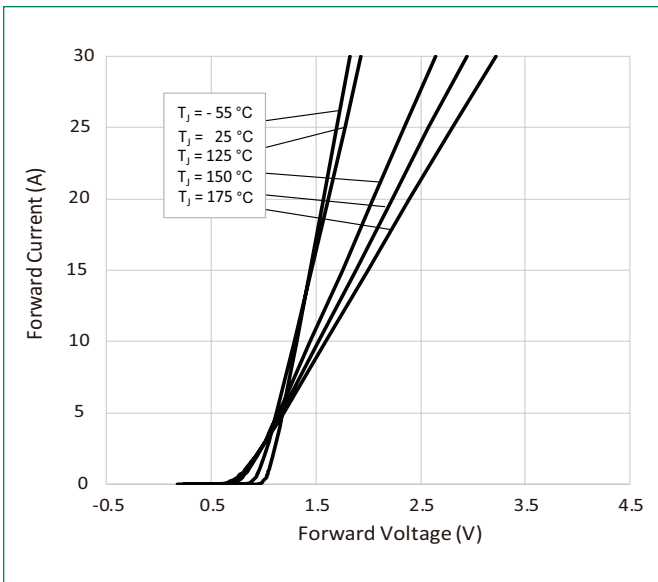
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	$V_F$	$I_F = 15\text{ A}, T_J = 25\text{ °C}$	-	1.5	1.8	V
		$I_F = 15\text{ A}, T_J = 175\text{ °C}$	-	2.2		
Reverse Current	$I_R$	$V_R = 1200\text{ V}, T_J = 25\text{ °C}$	-	<1	100	$\mu\text{A}$
		$V_R = 1200\text{ V}, T_J = 175\text{ °C}$	-	10		
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	920		pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	88		
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	64		
Total Capacitive Charge	$Q_C$	$V_R = 800\text{ V}, Q_C = \int_0^{V_R} C(V) dV$	-	92		nC

Footnote:  $T_J = +25\text{ °C}$  unless otherwise specified

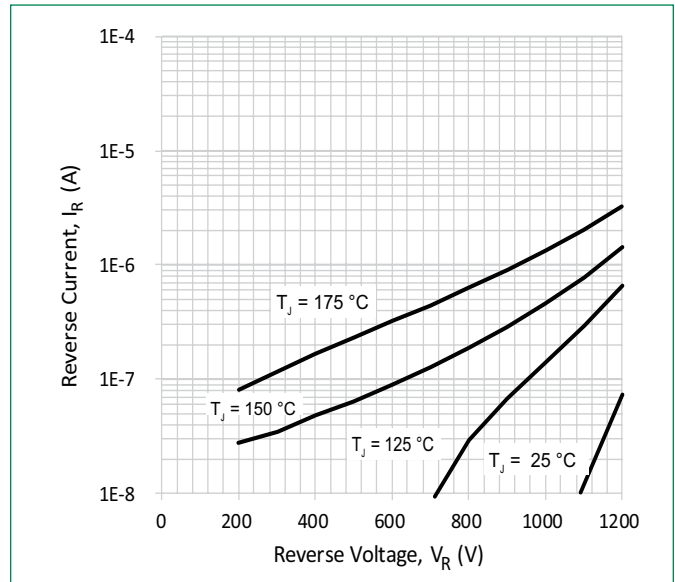
**Thermal Characteristics**

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance	$R_{\theta JC}$	-	-	0.7	-	$\text{°C/W}$

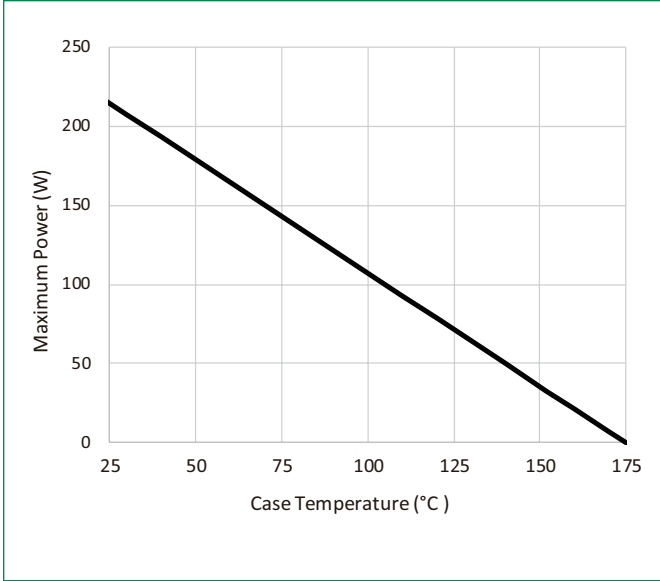
**Figure 1: Typical Forward Characteristics**



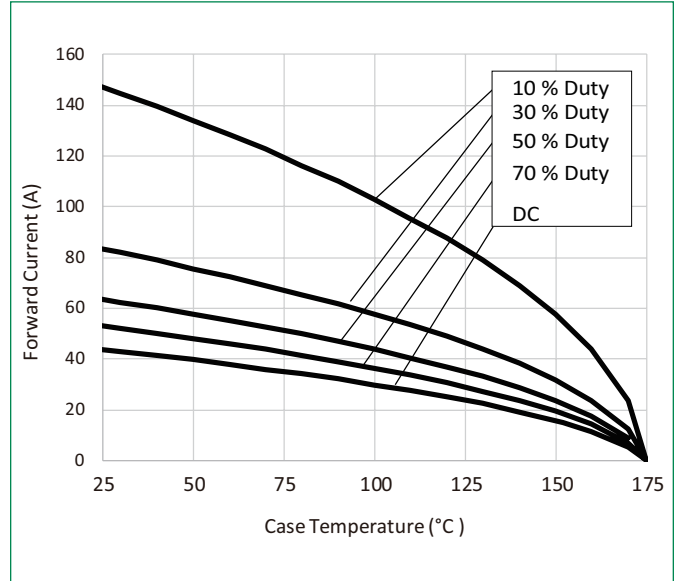
**Figure 2: Typical Reverse Characteristics**



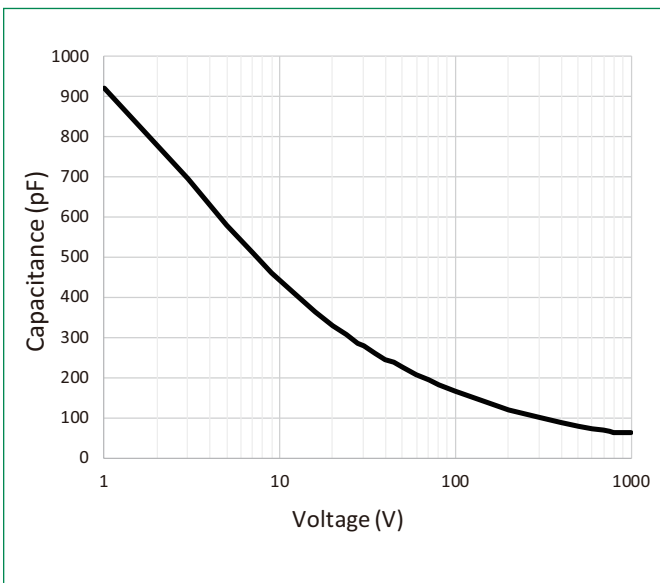
**Figure 3: Power Derating**



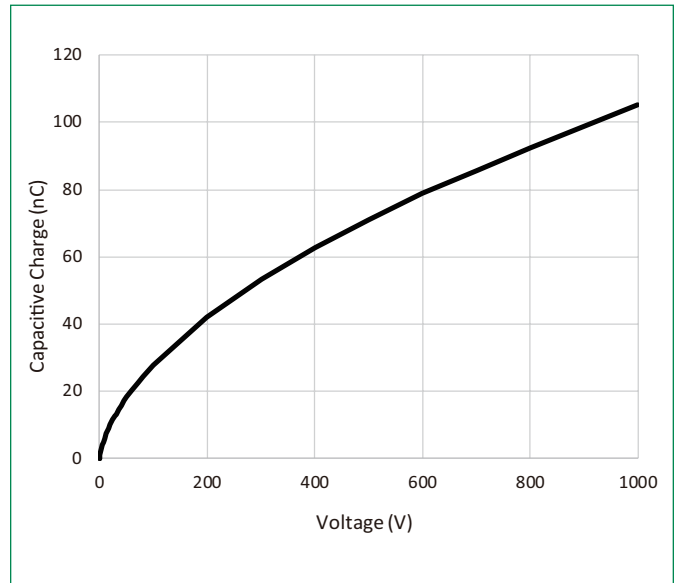
**Figure 4: Current Derating**



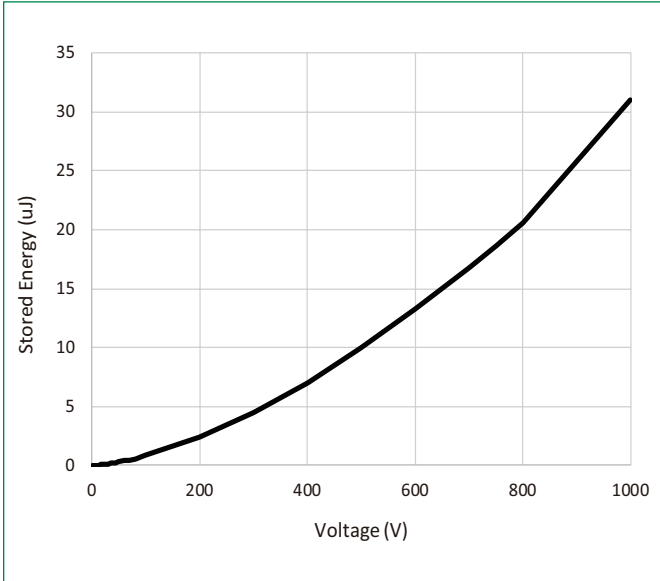
**Figure 5: Capacitance vs. Reverse Voltage**



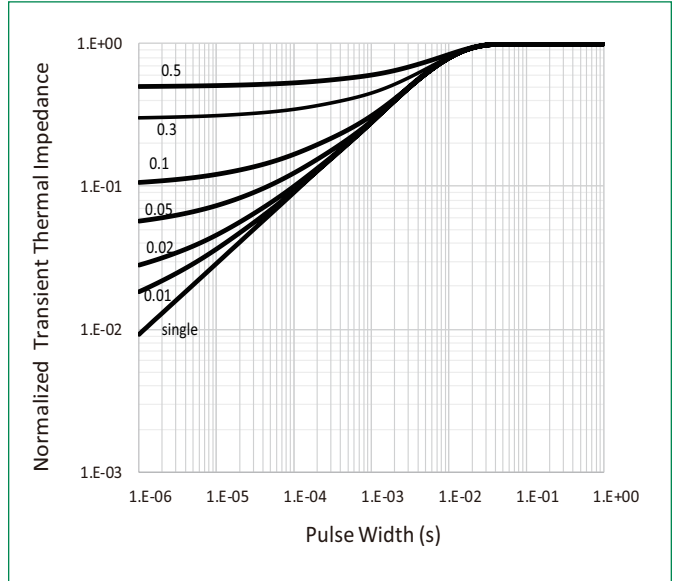
**Figure 6: Capacitive Charge vs. Reverse Voltage**



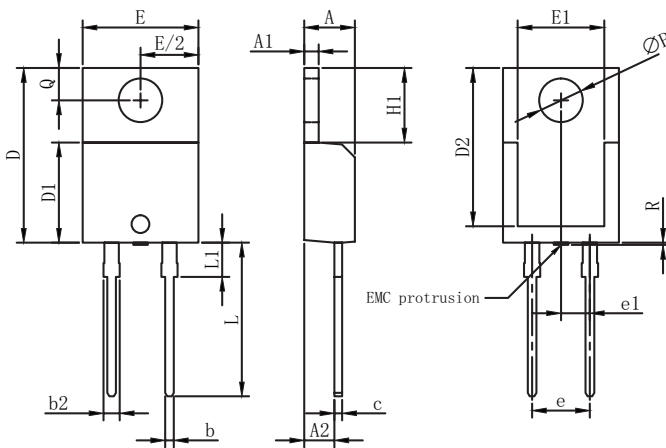
**Figure 7: Stored Energy vs. Reverse Voltage**



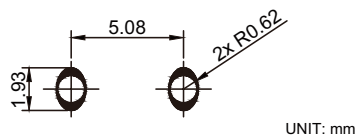
**Figure 8: Transient Thermal Impedance**



**Dimensions-Package TO-220-2L**

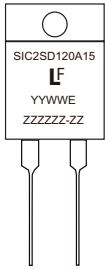


**Recommended Solder Pad Layout**



Symbol	Millimeters		
	Min	Nom	Max
A	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
c	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
E	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
e	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øP	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

**Part Numbering and Marking System**

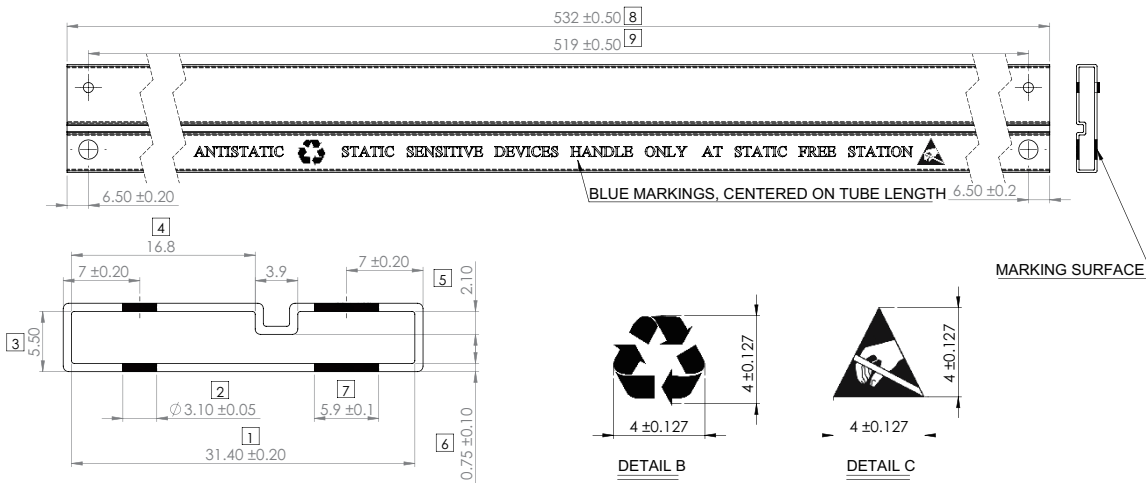


SIC = SiC Diode  
 2 = Gen2  
 SD = Schottky Diode  
 120 = Voltage Rating (1200 V)  
 A = TO-220 Package (2 Lead)  
 15 = Current Rating (15 A)  
 YY = Year  
 WW = Week  
 E = Special Code  
 ZZZZZZ-ZZ = Lot Number

**Packing Options**

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A15	SIC2SD120A15	Tube	1000

**Packing Specification ( Tube for TO-220-2L )**



- NOTES:
1. Material transparent extruded PVC with antistatic dipping
  2. Radius : 0.5 maximum unless otherwise specified
  3. Critical areas : Labelled in Box
  4. All pin plug holes are considered critical dimension
  5. Marking Font Type : Times new roman, 3.12 ± 0.127 in height
  6. Material Thickness : 0.75 ± 0.10
  7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°
  8. Unit : Millimeter (mm)

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